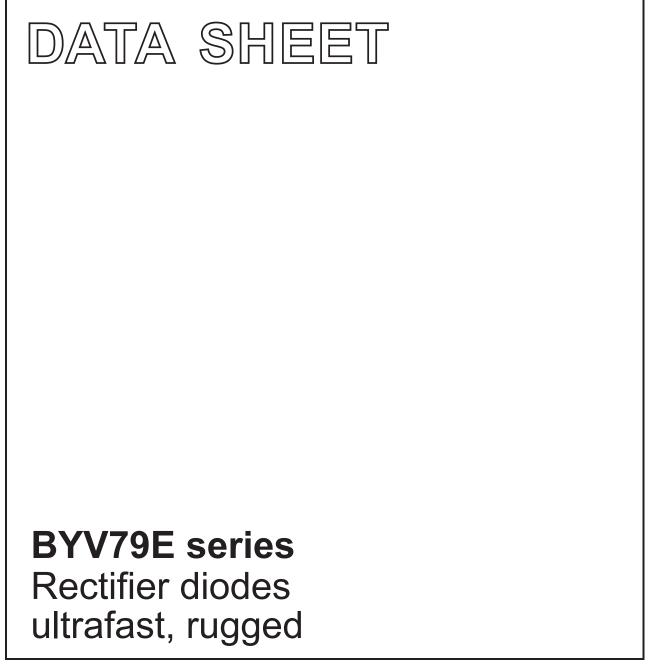
DISCRETE SEMICONDUCTORS



Product specification

September 2018



# **Rectifier diodes** ultrafast, rugged

## **FEATURES**

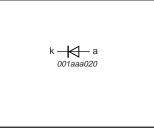
- Low forward volt drop
- Fast switching
- Soft recovery characteristic
- Reverse surge capability
- High thermal cycling performanceLow thermal resistance

### **GENERAL DESCRIPTION**

Ultra-fast, epitaxial rectifier diodes intended for use as output rectifiers in high frequency switched mode power supplies.

The BYV79E series is supplied in the conventional leaded SOD59 (TO220AC) package.

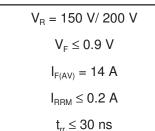
# **SYMBOL**



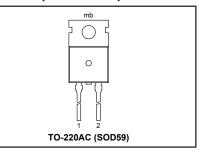
### PINNING

PIN	DESCRIPTION	
1	cathode	
2	anode	
tab	cathode	

# QUICK REFERENCE DATA



### SOD59 (TO220AC)



### LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MA	XX.	UNIT
V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	Peak repetitive reverse voltage Crest working reverse voltage Continuous reverse voltage	<b>BYV79E</b> T <sub>mb</sub> ≤ 145°C		<b>-150</b> 150 150 150	<b>-200</b> 200 200 200	<<<
I <sub>F(AV)</sub>	Average forward current <sup>1</sup>	square wave $\delta = 0.5$ ; T <sub>mb</sub> $\leq 120$ °C	-	1	4	A
I <sub>FRM</sub>	Repetitive peak forward current	t = 25 $\mu$ s; $\delta = 0.5$ ; T <sub>mb</sub> ≤ 120 °C	-	2	8	A
I <sub>FSM</sub>	Non-repetitive peak forward current	t = 10 ms t = 8.3 ms sinusoidal; with reapplied $V_{\text{RWM}(\text{max})}$ S = 0.001	-		50 50	A A
I <sub>RRM</sub> I <sub>RSM</sub>	Repetitive peak reverse current Non-repetitive peak reverse current	$t_p = 2 \ \mu s; \ \delta = 0.001$ $t_p = 100 \ \mu s$	-	0		A A
T <sub>stg</sub> T <sub>j</sub>	Storage temperature Operating junction temperature		-40 -		50 50	° ℃

1. Neglecting switching and reverse current losses.

### **ESD LIMITING VALUE**

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>c</sub>	Electrostatic discharge capacitor voltage	Human body model; C = 250 pF; R = 1.5 k $\Omega$	-	8	kV

**BYV79E series** 

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Rectifier diodes	
ultrafast, rugged	

BYV79E series

# THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
R <sub>th j-mb</sub>	Thermal resistance junction to		-	-	2	K/W
R <sub>th j-a</sub>	mounting base Thermal resistance junction to ambient	in free air	-	60	-	K/W

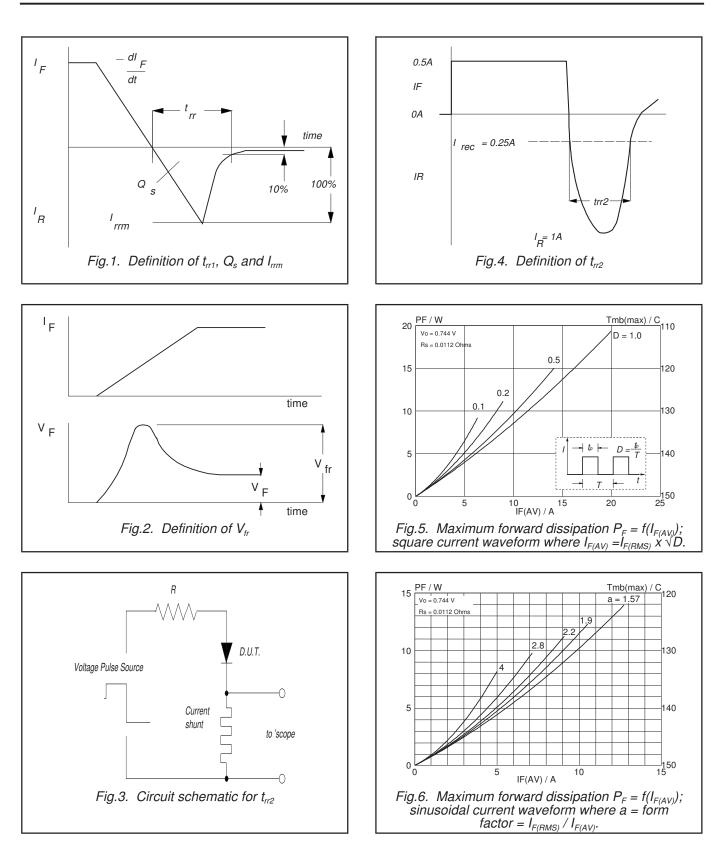
## STATIC CHARACTERISTICS

 $T_j = 25$  °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V <sub>F</sub>	Forward voltage	I <sub>F</sub> = 14 A; T <sub>i</sub> = 150°C	-	0.83	0.90	V
	-	$I_{\rm F} = 14  {\rm A}$	-	0.95	1.05	V
		$I_{\rm F} = 50  {\rm A}$	-	1.2	1.4	V
I <sub>B</sub>	Reverse current	$\dot{V}_{R} = V_{RWM}; T_{i} = 100 \ ^{\circ}C$	-	0.5	1.3	mA
		$V_{\rm P} = V_{\rm PWM}$	-	5	50	μA
Q <sub>s</sub>	Reverse recovery charge	$ I_{\rm F} = 2 \text{ A}; V_{\rm R} \ge 30 \text{ V}; -dI_{\rm F}/dt = 20 \text{ A}/\mu\text{s}$	-	6	15	'nC
t <sub>rr1</sub>	Reverse recovery time	$ I_{\rm F} = 1 \text{ A}; V_{\rm B} \ge 30 \text{ V};$	-	20	30	ns
		-dI <sub>F</sub> /dt = 100 A/µs				
t <sub>rr2</sub>	Reverse recovery time	$I_F = 0.5 \text{ A to } I_R = 1 \text{ A}; I_{rec} = 0.25 \text{ A}$ $I_F = 1 \text{ A}; dI_F/dt = 10 \text{ A}/\mu \text{s}$	-	13	22	ns
t <sub>rr2</sub> V <sub>fr</sub>	Forward recovery voltage	$I_{F} = 1 \text{ A}; dI_{F}/dt = 10 \text{ A}/\mu \text{s}$	-	1	-	V

# Rectifier diodes ultrafast, rugged

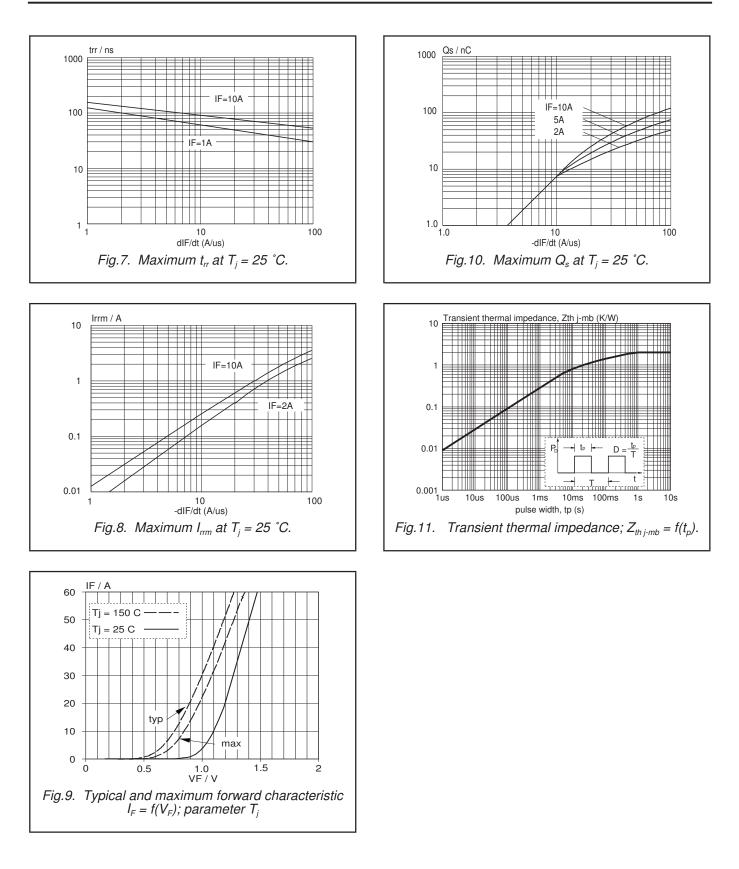
# BYV79E series



Product specification

**BYV79E** series

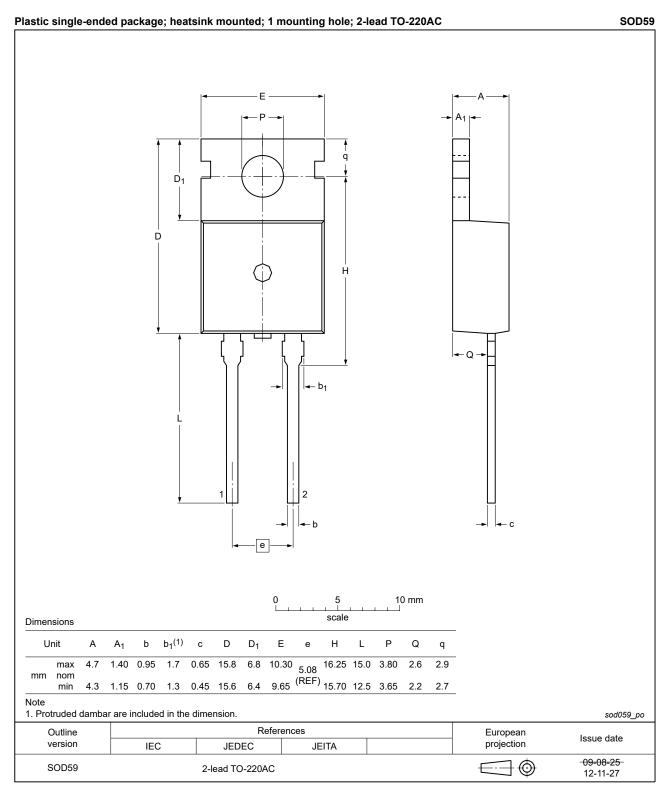
# Rectifier diodes ultrafast, rugged



**BYV79E** series

# Rectifier diodes ultrafast, rugged

### **MECHANICAL DATA**



# Legal information

#### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <u>http://www.ween-semi.com</u>.

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